

General Description

The MAX4617/MAX4618/MAX4619 are high-speed, lowvoltage, CMOS analog ICs configured as an 8-channel multiplexer (MAX4617), two 4-channel multiplexers (MAX4618), and three single-pole/double-throw (SPDT) switches (MAX4619).

These CMOS devices can operate continuously with a +2V to +5.5V single supply. Each switch can handle Rail-to-Rail® analog signals. The off-leakage current is only 1nA at $T_A = +25$ °C and 10nA at $T_A = +85$ °C.

All digital inputs have 0.8V to 2.4V logic thresholds, ensuring TTL/CMOS-logic compatibility when using a single +5V supply.

Applications

Battery-Operated Equipment

Audio/Video Signal Routing

Low-Voltage Data-Acquisition Systems

Communications Circuits

Features

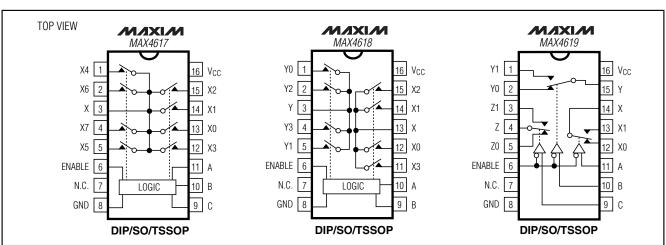
- ♦ Fast Switching Times 15ns ton 10ns toff
- ♦ Pin Compatible with Industry-Standard 74HC4051/74HC4052/74HC4053 and MAX4581/MAX4582/MAX4583
- ♦ Guaranteed On-Resistance 10 Ω max (+5V Supply) 20 Ω max (+3V Supply)
- ♦ Guaranteed 1Ω On-Resistance Match Between Channels (single +5V supply)
- **♦** Guaranteed Low Off-Leakage Current: 1nA at +25°C
- **Guaranteed Low On-Leakage Current:** 1nA at +25°C
- ♦ +2V to +5.5V Single-Supply Operation
- ♦ TTL/CMOS-Logic Compatible
- ♦ Low Crosstalk: <-96dB</p>
- ♦ High Off-Isolation: <-93dB</p>
- ♦ Low Distortion: <0.017% (600Ω)

Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX4617CUE	0°C to +70°C	16 TSSOP
MAX4617CSE	0°C to +70°C	16 Narrow SO
MAX4617CPE	0°C to +70°C	16 Plastic DIP

Ordering Information continued at end of data sheet.

Pin Configurations/Functional Diagrams



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

	_	
Voltages Referen	ced to GND	
Vcc, A, B, C, or	Enable	0.3V to +6V
Voltage into Any	Analog Terminal	
		0.3V to (V _{CC} + 0.3V)
		al±75mA
Peak Current, X_	, Y_, Z_	
**	, , ,	±200mA
	er Dissipation (T _A =	
TSSOP (derate	6.7mW/°C above +	-70°C)533mW

16-Pin QFN (derate 18.5mW/°C ab	ove +70°C)1481mW
Narrow SO (derate 8.70mW/°C abo	ove +70°C)696mW
Plastic DIP (derate 10.53mW/°C abo	ove +70°C)842mW
Operating Temperature Ranges	
MAX461_C	0°C to +70°C
MAX461_E	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10sec	e)+300°C

Note 1: Voltages exceeding V_{CC} or GND on any analog signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +5V Supply

(VCC = +4.5V to +5.5V, V_H = 2.4V, V_L = 0.8V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at TA = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS			TYP	MAX	UNITS
ANALOG SWITCH				•			
Analog-Signal Range	V_X , V_Y , V_Z		C, E	0		Vcc	V
Switch On-Resistance	Ron	V _{CC} = 4.5V; I _X , I _Y , I _Z = 10mA; V _X , V _Y , V _Z = 3V	T _A = +25°C		8	10	Ω
Switch on-Hesistance	HON		C, E			13	22
Switch On-Resistance		Vcc = 5V; Ix, Iy, Iz = 10mA;	T _A = +25°C		0.2	1	
Match Between	ΔR_{ON}	V _X , V _Y , V _Z = 3V	C, E			1.2	Ω
Channels (Notes 3,7)			0, 2				
Switch On-Resistance Flatness (Note 4)	RFLAT(ON)	$V_{CC} = 5V; I_X, I_Y, I_Z = 10mA;$ $V_X, V_Y, V_Z = 1V, 2V, 3V$	C, E			1	Ω
X_, Y_, Z_	IX_(OFF),	V _{CC} = 5.5V; V _X , V _Y , V _Z = 4.5V, 1V;	T _A = +25°C	-1	0.002	1	nA
Off-Leakage Current (Note 5)	IY_(OFF), IZ_(OFF)	V_X , V_Y , $V_Z = 1V$, $4.5V$	C, E	-10		10	- na
X, Y, Z Off-Leakage	IX(OFF),	V _{CC} = 5.5V; V _{EE} = -5.5V; V _X , V _Y , V _Z = 4.5V, 1V;	T _A = +25°C	-1	0.002	1	nA
Current (Note 5)	ly(OFF), lz(OFF)	VX_, VY_, VZ_ = 4.5V, 1V, VX, VY, VZ = 1V, 4.5V	C, E	-10		10	IIA
X, Y, Z On-Leakage	IX(ON),	V _{CC} = 5.5V; V _X , V _Y , V _Z = 1V, 4.5V;	T _A = +25°C	-1	0.002	1	nA
Current (Note 5)	ly(on), Iz(on)	V_{X} , V_{Y} , V_{Z} = 1V, 4.5V or floating	C, E	-10		10	1 IIA
DIGITAL I/O			·				
Input Voltage High	V _{AH} , V _{BH} , V _{CH} , VENABLEH		C, E	2.4			V
Input Voltage Low	V _{AL} , V _{BL} , V _{CL} , VENABLEL		C, E			0.8	V

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

 $(V_{CC} = +4.5V \text{ to } +5.5V, V_{H} = 2.4V, V_{L} = 0.8V, T_{A} = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_{A} = +25^{\circ}C.$) (Note 2)

PARAMETER	SYMBOL	CONDITIO	NS		MIN	TYP	MAX	UNITS	
Input Current High	IAH, IBH, ICH, IENABLE	VA, VB, VC = VENABLE = VCC		C, E	-1	0.0003	1	μΑ	
Input Current Low	I _{AL} , I _{BL} , I _{CL} , I _{ENABLE}	VA, VB, VC = VENABLE = 0		C, E	-1	0.0003	1	μΑ	
SWITCH DYNAMIC CHA	RACTERIS	TICS		•				•	
Enable Turn-On Time (Note 6)	ton	V_{X} , V_{Y} , V_{Z} = 3V; R_L = 300 Ω ; C_L Figure 3	= 35pF;	T _A = +25°C		7	15 18	- ns	
Enable Turn-Off Time (Note 6)	toff	V_{X} , V_{Y} , V_{Z} = 3V; R_L = 300 Ω ; C_L Figure 3	= 35pF;	T _A = +25°C C, E		4.5	10	ns	
Address Transition Time (Note 6)	t _{TRANS}	V_{X} , V_{Y} , V_{Z} = 3V; R_L = 300 Ω ; C_L Figure 2	= 35pF;	T _A = +25°C C, E		7	15 18	ns	
Break-Before-Make Time (Note 6)	t _{BBM}	V_{X} , V_{Y} , V_{Z} = 3V; R_L = 300 Ω ; C_L = 35pF; Figure 4		T _A = +25°C	0.2	1.5		ns	
Charge Injection	Q	$C = 1nF, R_S = 0, V_S = 0, Figure 5$		T _A = +25°C		3		рС	
Input Off-Capacitance	CX_(OFF), CY_(OFF), CZ_(OFF)	V _{X_} , V _{Y_} , V _{Z_} = 0; f = 1MHz; Figure 7		T _A = +25°C		5		pF	
	C _{X(OFF)} ,	V V O C 4MI	MAX4617			27			
Output Off-Capacitance	C _{Y(OFF)} ,	Vx_, Vy_, Vz_ = 0; f = 1MHz; Figure 7	MAX4618	$T_A = +25^{\circ}C$		15		pF	
	C _{Z(OFF)}		MAX4619			8.5			
0.44 0- 0	C _{X(ON)} ,	Vx_, Vy_, Vz_ = 0; f = 1MHz;	MAX4617	T 0500		32			
Output On-Capacitance	C _{Y(ON)} , C _{Z(ON)}	Figure 7	MAX4618 MAX4619	$T_A = +25$ °C		21 15.5		pF	
Off-Isolation	VISO	$R_{\rm L} = 50\Omega$, $f = 100$ kHz, Figure 6		T _A = +25°C		-93		dB	
Channel-to-Channel Crosstalk	V _{CT}	$R_L = 50\Omega$, $f = 100$ kHz, Figure 6		$T_A = +25^{\circ}C$		-96		dB	
Total Harmonic Distortion	THD	$R_L = 600\Omega$, 1Vp-p, f = 20Hz to 20kHz T_A		T _A = +25°C		0.017		%	
POWER SUPPLY									
Power-Supply Range	Vcc			C, E	+2		+5.5	V	
Power-Supply Current	Icc	V _{CC} = 5.5V; V _A , V _B , V _C , V _{ENABLE} =	· VCC or 0	T _A = +25°C C, E	-1 -10		10	μΑ	

ELECTRICAL CHARACTERISTICS—Single +3.3V Supply

 $(V_{CC} = +3V \text{ to } +3.6V, V_{H} = 2.0V, V_{L} = 0.5V, T_{A} = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_{A} = +25^{\circ}C.$) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog-Signal Range	Vx_, Vy_, Vz_, Vx, Vy, Vz		C, E	0		V _C C	V
Switch On-Resistance	Ron	V _{CC} = 3V; I _X , I _Y , I _Z = 10mA; V _X , V _Y , V _Z = 1.5V	T _A = +25°C C, E		8	20 25	Ω
		vx, vy, v∠ = 1.5v					
X_, Y_, Z_ Off-Leakage	IX_(OFF), IY_(OFF),	$V_{CC} = 3.6V; V_{X}, V_{Y}, V_{Z} = 1V, 3V;$	T _A = +25°C	-1	0.002	1	nA
Current (Note 5)	IZ_(OFF)	V_X , V_Y , $V_Z = 3V$, $1V$	C, E	-10		10	
X, Y, Z Off-Leakage	IX(OFF),	V _{CC} = 3.6V; V _{X_} , V _{Y_} , V _{Z_} = 1V, 3V;	T _A = +25°C	-1	0.002	1	
Current (Note 6)	ly(OFF), lz(OFF)	V_X , V_Y , $V_Z = 3V$, $1V$	C, E	-10		10	- nA
X, Y, Z On-Leakage	IX(ON),	Vcc = 3.6V; Vx, Vy, Vz = 3V, 1V;	T _A = +25°C	-1	0.002	1	
Current (Note 6)	ly(on), Iz(on)	V_{X} , V_{Y} , V_{Z} = 3V, 1V, or floating	C, E	-10		10	nA
DIGITAL I/O							
Input Voltage High	V _{AH} , V _{BH} , V _{CH} , V _{ENABLEH}		C, E	2.0			V
Input Voltage Low	V _{AL} , V _{BL} , V _{CL} , V _{ENABLEL}		C, E			0.5	V
Input Current High	IAH, IBH, ICH, IENABLEH	VA, VB, VC = VENABLE = VCC	C, E	-1	0.0003	1	μΑ
Input Current Low	IAL, IBL, ICL, IENABLEL	V _A , V _B , V _C = V _{ENABLE} = 0	C, E	-1	0.0003	1	μΑ
SWITCH DYNAMIC CH	ARACTERISTIC	S	l				
Enable Turn-On Time (Note 6)	ton	V_{X} , V_{Y} , V_{Z} = 1.5V; R_L = 300 Ω ; C_L = 35pF; Figure 3	T _A = +25°C C, E		9	20 25	ns
Enable Turn-Off Time		$V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 1.5V; R_{L} = 300\Omega;$	$T_A = +25^{\circ}C$		6	15	
(Note 6)	tOFF	$C_L = 35pF$; Figure 3	C, E			20	ns
Address Transition	ttDANC.	$V_{X}, V_{Y}, V_{Z} = 1.5V/0; R_L = 300\Omega;$	T _A = +25°C		9	20	
Time (Note 6)	ttrans	C _L = 35pF; Figure 2	C, E			25	ns
Break-Before-Make Time (Note 6)	t _{BBM}	$V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 1.5V; R_{L} = 300\Omega; C_{L} = 35pF$	T _A = +25°C	0.2	1.5		ns
Charge Injection (Note 6)	Q	$C = 1nF, R_S = 0, V_S = 0, Figure 5$	T _A = +25°C		3		рС
POWER SUPPLY							1
Power-Supply Current	I _{CC}	V _{CC} = 3.6V, V _A , V _B , V _C , V _{ENABLE} = V _{CC} or 0	T _A = +25°C			1 10	μΑ

ELECTRICAL CHARACTERISTICS—Single +2.5V Supply

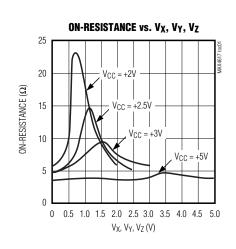
 $(V_{CC} = +2.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C.)$ (Note 2)

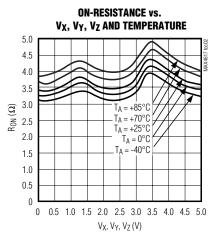
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Switch On-Resistance	Ron	V _{CC} = 2.5V; I _X , I _Y , I _Z = 10mA;	$T_A = +25^{\circ}C$		30	60	Ω
Switch On-Hesistance	HON	V_X , V_Y , $V_Z = 1.2V$	C, E			100	
SWITCH DYNAMIC CH	ARACTERISTIC	S	1				
Enable Turn-On Time (Note 6)	ton	V_{X} , V_{Y} , V_{Z} = 1V; R_L = 300 Ω ; C_L = 35pF; Figure 3	T _A = +25°C		12		ns
Enable Turn-Off Time (Note 6)	toff	V_{X} , V_{Y} , V_{Z} = 1V; R_L = 300 Ω ; C_L = 35pF; Figure 3	T _A = +25°C		10		ns
Address Transition Time (Note 6)	t _{TRANS}	V_{X} , V_{Y} , V_{Z} = 1V; R_L = 300 Ω ; C_L = 35pF; Figure 3	T _A = +25°C		12		ns

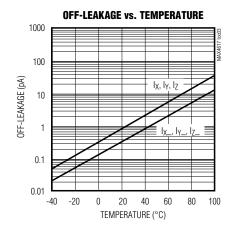
- Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.
- **Note 3:** $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- **Note 4:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges; i.e., Vx_, Vy_, Vz_ = 3V to 0 and 0 to -3V.
- Note 5: Leakage parameters are 100% tested at maximum-rated hot operating temperature, and guaranteed by correlation at T_A = +25°C.
- Note 6: Guaranteed by design, not production tested.
- Note 7: ΔR_{ON} matching specifications for QFN-packaged parts are guaranteed by design.

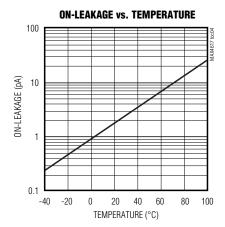
Typical Operating Characteristics

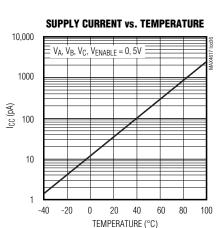
 $(V_{CC} = +5V, GND = 0, T_A = +25^{\circ}C, unless otherwise noted.)$

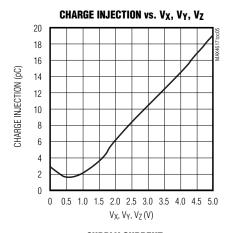


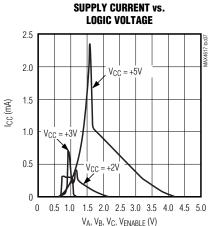






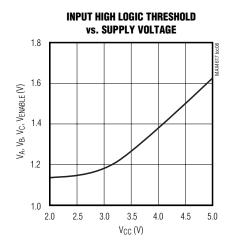


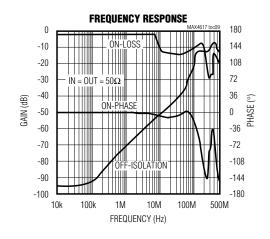


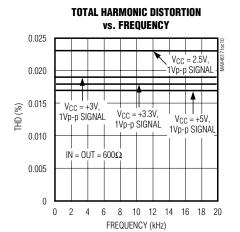


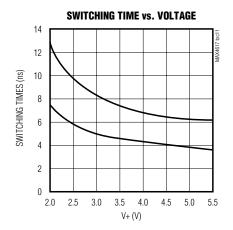
Typical Operating Characteristics (continued)

($V_{CC} = +5V$, GND = 0, $T_A = +25$ °C, unless otherwise noted.)









Pin Description

	PIN			
MAX4617	MAX4618	MAX4619	NAME	FUNCTION
13, 14, 15, 12, 1, 5, 2, 4	_	_	X0-X7	Analog Switch Inputs 0–7
3	_	_	X	Analog Switch Output
_	12, 14, 15, 11	_	X0, X1, X2, X3	Analog Switch "X" Inputs 0-3
_	13	14	X	Analog Switch "X" Output
_	_	13	X1	Analog Switch "X" Normally Open Input
_	_	12	X0	Analog Switch "X" Normally Closed Input
_	_	1	Y1	Analog Switch "Y" Normally Open Input
_	_	2	Y0	Analog Switch "Y" Normally Closed Input
6	6	6	ENABLE	Digital Enable Input. Normally connect to GND. Can be driven to logic high to set all switches off.
7	7	7	N.C.	No Connection. Not Internally connected.
8	8	8	GND	Ground
11	10	11	А	Digital Address "A" Input
10	9	10	В	Digital Address "B" Input
9	_	9	С	Digital Address "C" Input
_	1, 5, 2, 4	_	Y0, Y1, Y2, Y3	Analog Switch "Y" Inputs 0-3
_	3	15	Υ	Analog Switch "Y" Output
_	_	5	Z0	Analog Switch "Z" Normally Closed Input
_	_	3	Z1	Analog Switch "Z" Normally Open Input
_	_	4	Z	Analog Switch "Z" Output
16	16	16	Vcc	Positive Analog and Digital Supply Voltage Input

Note: Input and output pins are identical and interchangeable. Any may be considered an input or output; signals pass equally well in both directions.

Applications Information Power-Supply Considerations

Overview

The MAX4617/MAX4618/MAX4619 construction is typical of most CMOS analog switches. They have two supply pins: VCC and GND. VCC and GND are used to drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD-protection diodes are internally connected between each analog-signal pin and both VCC and GND. If any analog signal exceeds VCC or GND, one of these diodes conducts. During normal operation, these and other reverse-biased ESD diodes leak, forming the only current drawn from VCC or GND.

Virtually all the analog leakage current comes from the ESD diodes. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse biased differently. Each is biased by either VCC or GND and the analog signal. This means their leakages will vary as the signal varies. The difference in the two diode leakages to the VCC and GND pins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of either the same or opposite polarity.

VCC and GND power the internal logic and set the input logic limits. Logic inputs have ESD-protection diodes to ground.

The logic-level thresholds are TTL/CMOS compatible when V_{CC} is +5V. As V_{CC} rises, the threshold increases; as V_{CC} falls, the threshold decreases. For example, when V_{CC} = +3V the guaranteed minimum logic-high threshold decreases to 2.0V

Power Supply

These devices operate from a single supply between +2.5V and +5.5V. All of the bipolar precautions must be observed. At room temperature, they actually "work" with a single supply near or below +2V, although as supply voltage decreases, switch on-resistance becomes very high.

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence VCC on first, followed by the logic inputs and analog signals. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with the supply pins for overvoltage protection (Figure 1).

Adding diodes reduces the analog-signal range to one diode drop below V_{CC} and one diode drop above GND, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V_{CC} and GND should not exceed 6V. These protection diodes are not recommended if signal levels must extend to ground.

High-Frequency Performance

In 50Ω systems, signal response is reasonably flat up to 50MHz (see *Typical Operating Characteristics*). Above 20MHz, the on-response has several minor peaks that are highly layout dependent. The problem is not turning the switch on, but turning it off. The off-state switch acts like a capacitor and passes higher frequencies with less attenuation. At 10MHz, off-isolation is about -50dB in 50Ω systems, becoming worse (approximately 20dB per decade) as frequency increases. Higher circuit impedances also degrade off-isolation. Adjacent channel attenuation is about 3dB above that of a bare IC socket and is entirely due to capacitive coupling.

Pin Nomenclature

The MAX4617/MAX4618/MAX4619 are pin compatible with the industry-standard 74HC4051/74HC4052/74HC4053 and the MAX4581/MAX4582/MAX4583. In single-supply applications, they function identically and have identical logic diagrams, although these parts differ electrically.

The pin designations and logic diagrams in this data sheet conform to the original 1972 specifications published by RCA for the CD4051/CD4052/CD4053. These designations differ from the standard Maxim switch and mux designations found on other Maxim data sheets (including the MAX4051/MAX4052/MAX4053) and may cause confusion. Designers who feel more comfortable with Maxim's standard designations are advised that the pin designations and logic diagrams on the MAX4051/MAX4052/MAX4053 data sheet may be freely applied to the MAX4617/MAX4618/MAX4619.

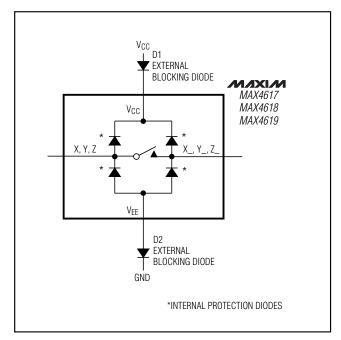


Figure 1. Overvoltage Protection Using External Blocking Diodes

Table 1. Truth Table/Switch Programming

ENABLE	SI	SELECT INPUTS			ON SWITCHES	
INPUT	C*	В	Α	MAX4617	MAX4618	MAX4619
Н	Х	X	X	All switches open	All switches open	All switches open
L	L	L	L	X–X0	X–X0, Y–Y0	X–X0, Y–Y0, Z–Z0
L	L	L	Н	X–X1	X–X1, Y–Y1	X–X1, Y–Y0, Z–Z0
L	L	Н	L	X–X2	X–X2, Y–Y2	X–X0, Y–Y1, Z–Z0
L	L	Н	Н	X–X3	X-X3, Y-Y3	X–X1, Y–Y1, Z–Z0
L	Н	L	L	X-X4	X–X0, Y–Y0	X–X0, Y–Y0, Z–Z1
L	Н	L	Н	X-X5	X–X1, Y–Y1	X–X1, Y–Y0, Z–Z1
L	Н	Н	L	X–X6	X–X2, Y–Y2	X–X0, Y–Y1, Z–Z1
L	Н	Н	Н	X–X7	X-X3, Y-Y3	X–X1, Y–Y1, Z–Z1

X = Don't care

Note: Input and output pins are identical and interchangeable. Either may be considered an input or output; signals pass equally well in either direction.

^{*}C not present on MAX4618.

Test Circuits/Timing Diagrams

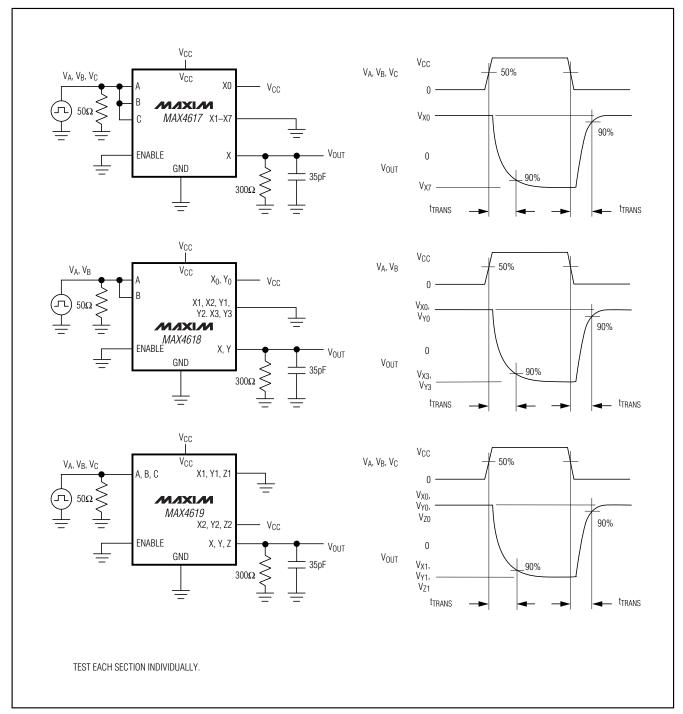


Figure 2. Address Transition Times

Test Circuits/Timing Diagrams (continued)

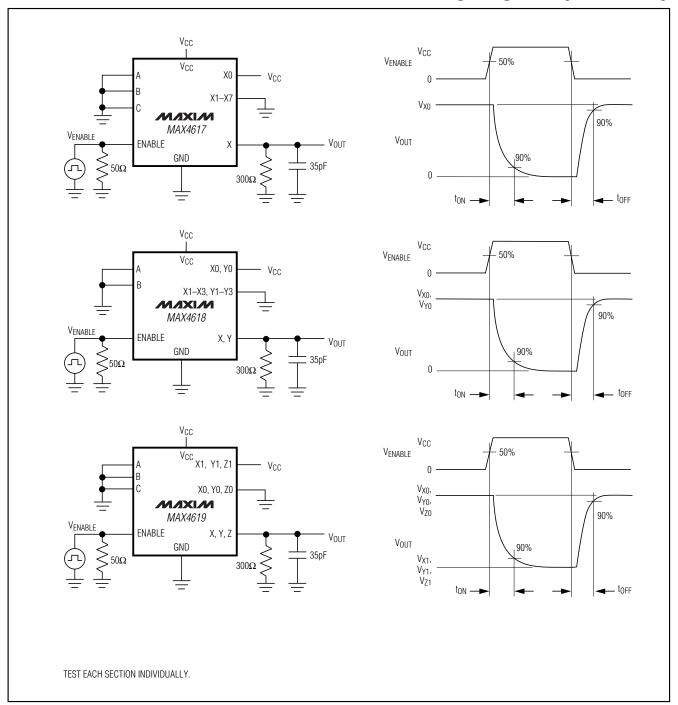


Figure 3. Enable Switching Times

Test Circuits/Timing Diagrams (continued)

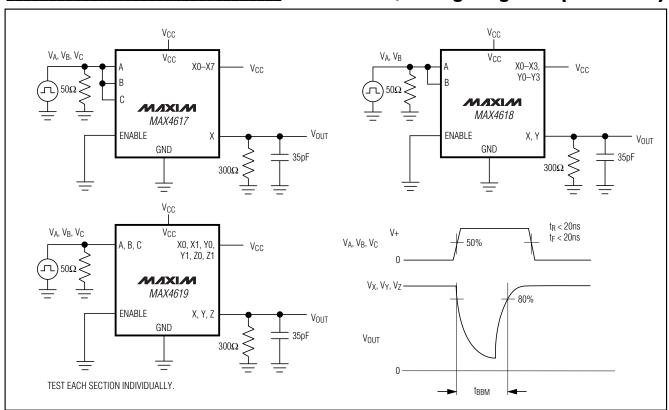


Figure 4. Break-Before-Make Interval

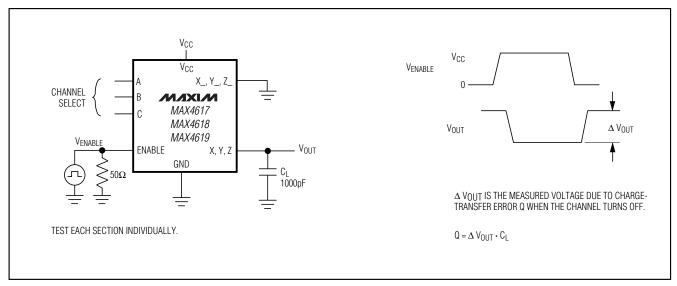


Figure 5. Charge Injection

Test Circuits/Timing Diagrams (continued)

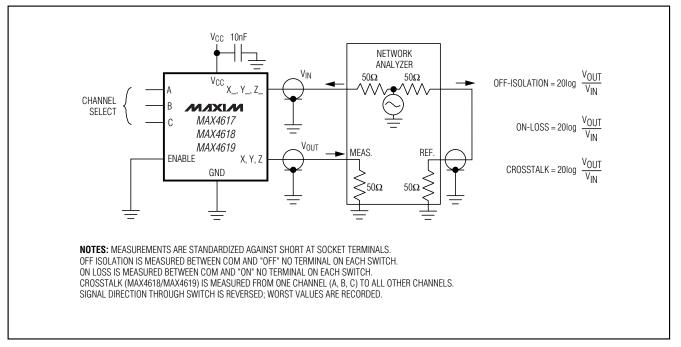


Figure 6. Off-Isolation, On-Loss, and Crosstalk

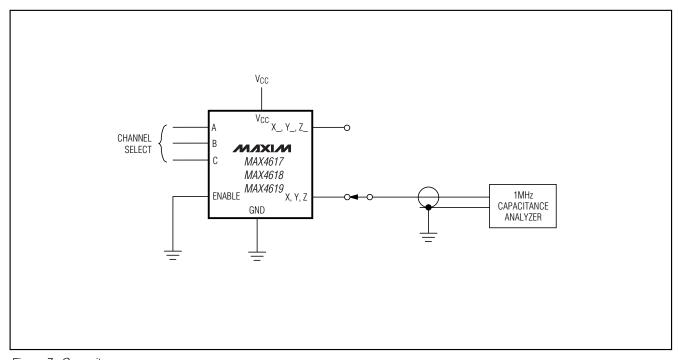
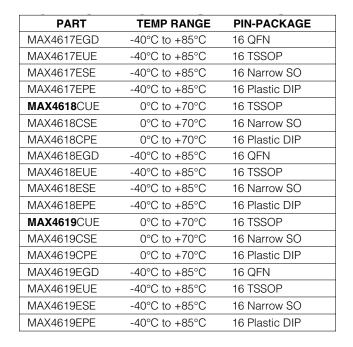


Figure 7. Capacitance

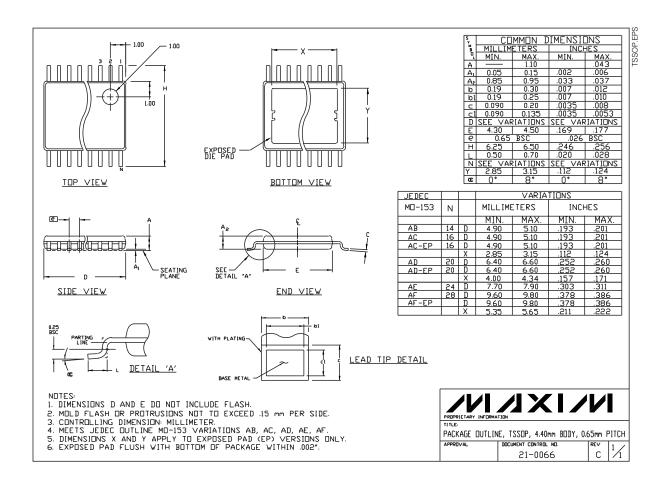
Chip I	ntormation
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TRANSISTOR COUNT: 244



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information,



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